

Central™ Semiconductor Corp.

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Manufacturers of World Class Discrete Semiconductors
www.centralsemi.com

CN645 THRU CN649

**GLASS PASSIVATED JUNCTION
GENERAL PURPOSE DIODE**

DO-41SP CASE

DESCRIPTION

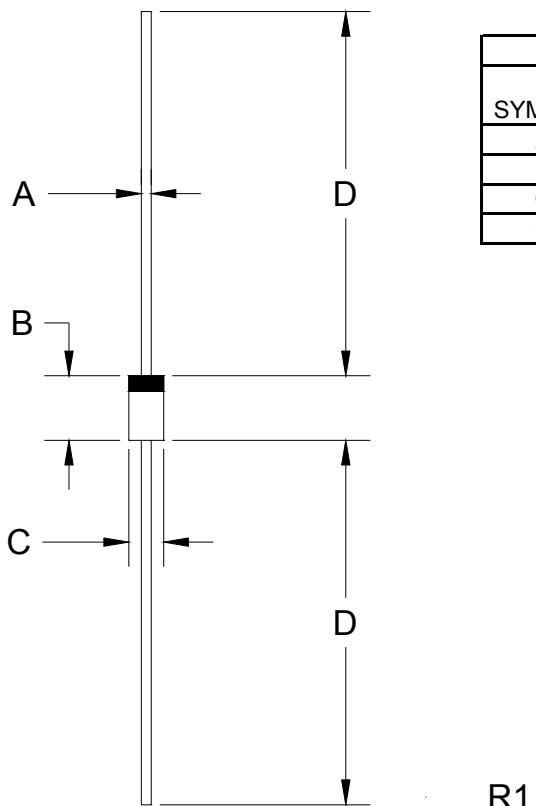
The CENTRAL SEMICONDUCTOR CN645 Series types are Glass Passivated Junction general-purpose diodes, which are well constructed, highly reliable components designed for use in all types of commercial, industrial, entertainment, computer and automotive applications.

MAXIMUM RATINGS (T_A=25°C unless otherwise noted)

	<u>SYMBOL</u>	<u>CN645</u>	<u>CN646</u>	<u>CN647</u>	<u>CN648</u>	<u>CN649</u>	<u>UNITS</u>
Peak Working Reverse Voltage	V _{RWM}	225	300	400	500	600	V
Average Forward Current	I _O			400			mA
Average Forward Current (T _A =150°C)	I _O			150			mA
Peak Forward Surge Current	I _{FSM}			3.0			A
Power Dissipation	P _D			600			mW
Operating and Storage Junction Temperature	T _J , T _{stg}			-65 to 150			°C

ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise noted)

<u>SYMBOL</u>	<u>TEST CONDITIONS</u>	<u>CN645</u>		<u>CN646</u>		<u>CN647</u>		<u>CN648</u>		<u>CN649</u>		<u>UNITS</u>
		<u>MIN</u>	<u>MAX</u>									
V _{BR}	I _R =100µA, T _A =100°C	275		360		480		600		720		V
I _R	V _R =RATED V _{RWM} , T _A =100°C		15		15		20		20		25	µA
I _R	V _R =RATED V _{RWM}		0.2		0.2		0.2		0.2		0.2	µA
V _F	I _F =400mA		1.0		1.0		1.0		1.0		1.0	V
C _T	V _R =12V, f=1.0MHz	11 TYP		pF								

DO-41SP PACKAGE - MECHANICAL OUTLINE

SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.021	0.025	0.53	0.64
B	0.160	0.205	4.06	5.21
C	0.080	0.107	2.03	2.72
D	1.000	-	25.40	-

DO-41SP (REV: R1)

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